

Shipped in packet-tape reel(5000pcs/Reel)

AK8772 is ultra-small Hall effect IC of a single silicon chip composed of Hall element and a signal processing IC.

Bipolar Hall	Supply Voltage	Power down	Ultra High	Output	SON	
Effect Latch	1.6~5.5V	Function	Sensitivity Bop:1.8mT	CMOS		

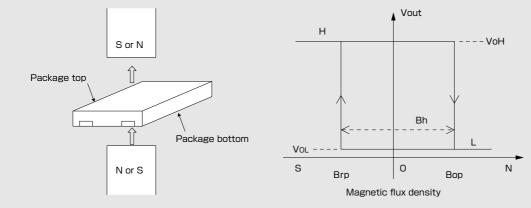
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Features

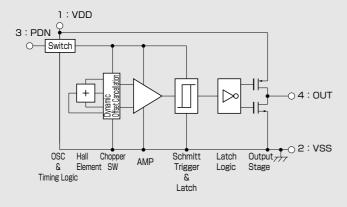
- \cdot Precision Bipolar Hall Effect Latch
- \cdot Power manageability through "PDN" pin Current consumption in Power down mode is less than 1 μ A
- Low current consumption at active mode : less than avg. 150μ A@VDD=3V
- · Ultra small SON package : 1.1×1.4×t0.37mm, Halogen free

Operational Characteristics





Functional Block Diagram



Item	Function
osc	Generates operating clock
Timing logic	Generates timing signal requires for Chopper SW, AMP and COMP
Hall Element	Hall element fabricated by CMOS process
Chopper SW	Performs chopping in order to cancel the offset voltage of Hall sensor
AMP	Reduce offset voltage and amplifies Hall output voltage
Schmitt Trigger	Hysteresis comparator
Output Stage	CMOS output, During the power down mode, output is latched in its previous state

ASAHI KASEI MICRODEVICES

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Absolute Maximum Ratings

Item	symbol	Min.	Max.	Unit	Note
Power supply voltage	V _{DD}	-0.3	+6.5	V	
Output current	I _{OUT}	-0.5	+0.5	mA	OUT pin
Input voltage	VIN	-0.3	V _{DD} +0.3*	V	PDN pin
Input current	IIN	-10	+10	mA	PDN pin
Storage temperature	T _{STG}	-55	+125	°C	

*) Less than +6.5V.

Note) Stress beyond these listed values may cause permanent damage to the device.

Recommended Operating Conditions

Item	symbol	Min.	Typ.	Max.	Unit
Power supply voltage	V _{DD}	1.6	3.0	5.5	V
Operating temperature	T _a	-30		+85	C

Electrical Characteristics (Ta=25°C VDD=3.0V)

Item	symbol	Min.	Тур.	Max.	Unit	Note
Current consumption 1	I _{DD1}			1	μA	PDN=0V
Current consumption 2	I _{DD2}		60	150	μA	PDN=V _{DD,} Average
PDN Input current	I _{IN}	-1		1	μA	
PDN input H voltage	V _{IH}	0.7V _{DD}			V	
PDN input L voltage	V _{IL}			0.3	V	
High Level output voltage	V _{OH}	V _{DD} -0.4			V	I _{out} =-0.5mA
Low level output voltage	V _{OL}			0.4	V	I _{out} =+0.5mA
PDN mode transition time 1	T _{PD1}			(36.6)	μs	*Active→PDN
PDN mode transition time 2	T _{PD2}			100	μs	PDN→Active
Pulse drive period	T _{PD3}	0.5	1.0	1.5	ms	When $PDN = V_{DD}$
Pulse drive time	T _{PD4}	12.2	24.4	36.6	μs	
PDN 'H' input pulse width	Tw	100			μS	

*)This transition time is not guaranteed by inspection because PDN input timing and internal timing are asynchronous

●Magnetic Characteristics① (Ta=25℃ VDD=3.0V)

Item	symbol	Min.	Тур.	Max.	Unit
Operating point	B _{op}		1.8	4.0	mT
Releasing point	B _{rp}	-4.0	-1.8		mT
Hysteresis	B _h		3.6		mT

●Magnetic Characteristics② (Ta=-30°C~85°C VDD=1.6~5.5V)

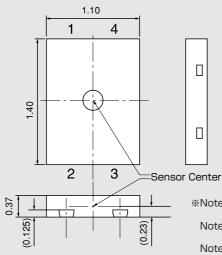
Item	symbol	Min.	Тур.	Max.	Unit
Operating point	B _{op}		1.8	4.2	mT
Releasing point	B _{rp}	-4.2	-1.8		mT
Hysteresis	B _h		3.6		mT

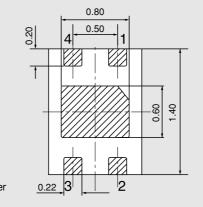
Note) The specifications in Magnetic Characteristics (2) are design targets.

С

n

Package (Unit:mm)





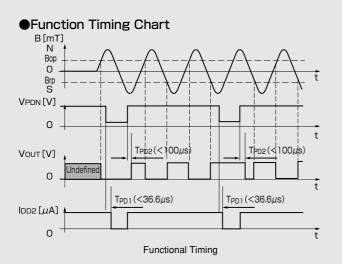
**Note 1) Sensitive area position referenced to the center of package within ϕ O.3mm circle.

Note 2) Tolerances of dimension otherwise noted is $\pm 0.05 \text{mm.}$

Note 3) Hatched area is plated.

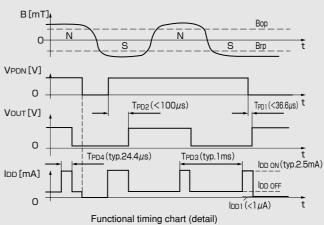
Note 4) Center pad area (TAB) should be tied to the VSS or floating

	No.	Pin name	Function	Note
	1	VDD	Power supply pin	
Γ	2	VSS	Ground pin	
Γ	3	PDN	Power down pin.	CMOS Input. This pin has to be
I			H:Device active	tied to "H" level when external
I			L:Device power down	power control is not used.
Γ	4	OUT	Output pin	CMOS Output



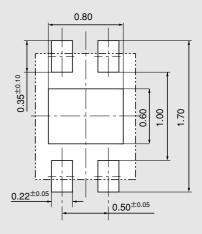


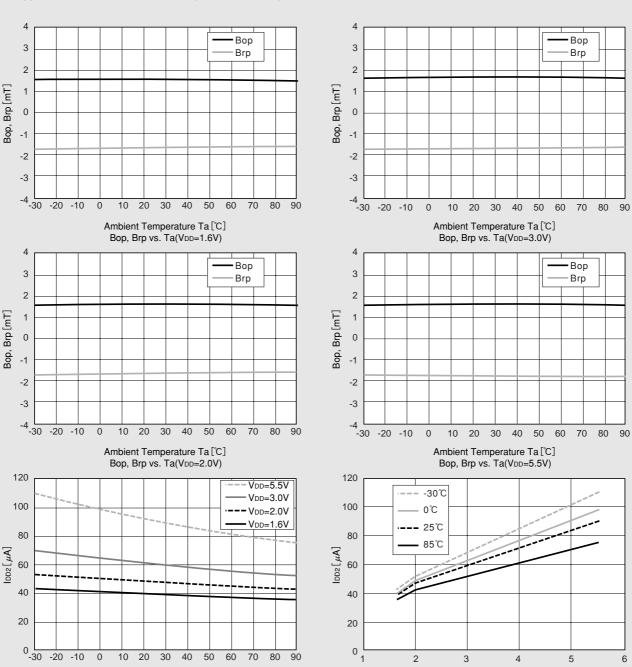
Note2) When VDD is supplied, the time from reaching VDD= 1.6V to the update of the output state is equal to TPD2.



When PDN pin set to 'L' from 'H' during sampling is performing, the device transits to power down mode after sampling is completed. And when PDN pin set to 'L' from 'H' while sampling is not performing, the device transits to power down mode immediately.

Footprint (for reference)

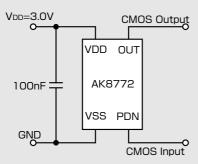




•Typical Characteristic Data (for reference)







g

k

0 р

n

6

VDD [V]

IDD2 vs.VDD Ta(in various Ta)

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